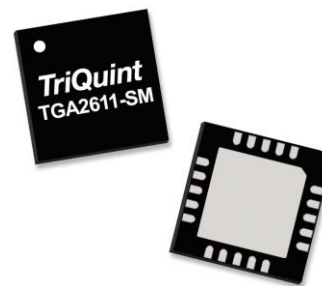


Applications

- Commercial and Military Radar
- Communications



Product Features

- Frequency Range: 2 – 6 GHz
- NF: 1.0 dB
- OTOI: 30 dBm at Pout/tone = 18 dBm
- Small Signal Gain: 22 dB
- Return Loss: >10 dB
- P1dB: 18 dBm, $P_{SAT} = 26$ dBm at $P_{IN} = 10$ dBm
- Bias: $V_D = 10$ V, $I_{DQ} = 100$ mA, $V_G = -2.3$ V
- Package Dimensions: 4.0 x 4.0 x 0.85 mm

General Description

TriQuint's TGA2611-SM is a packaged broadband Low Noise Amplifier fabricated on TriQuint's TQGaN25 0.25 μ m GaN on SiC process. The TGA2611-SM operates from 2 to 6 GHz and typically provides >18 dBm P1dB, >22 dB of small signal gain and 30 dBm of OTOI with 1.0 dB NF. In addition to the high overall electrical performance, this GaN amplifier also provides a high level of input power robustness which allows more flexibility in designing the receive chain circuit protection.

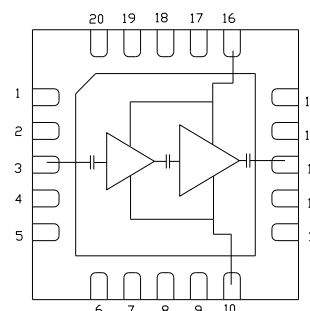
The TGA2611-SM is available in a low cost, surface mount 20-lead 4x4 mm plastic QFN. It is ideally suited to support both radar and satellite communication applications.

Both RF ports have intergraded DC blocking caps and are fully matched to 50 ohms.

Lead-free and RoHS compliant

Evaluation Boards are available upon request.

Functional Block Diagram



Pad Configuration

Pad No.	Symbol
1, 2, 4-9, 11, 12, 14, 15, 17-20	N/C
3	RF_{IN}
10	V_G
13	RF_{OUT}
16	V_D

Ordering Information

Part	ECCN	Description
TGA2611-SM	EAR99	2 – 6 GHz GaN LNA

Absolute Maximum Ratings

Parameter	Value
Drain Voltage (V_D)	40 V
Gate Voltage Range (V_G)	-5 to 0 V
Drain Current (I_D)	300 mA
Gate Current (I_G)	-1 to 4 mA
Power Dissipation, 85 °C (P_{DISS})	6 W
Input Power, CW, 50 Ω , (P_{IN})	30 dBm
Channel temperature (T_{CH})	275 °C
Mounting Temperature (30 Seconds)	260 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Value
Drain Voltage (V_D)	10 V
Drain Current (I_{DQ})	100 mA
Gate Voltage (V_G)	-2.3 V Typical
Temperature (T_{BASE})	-40 to 85 °C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed overall operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: 25 °C, V_D = 10V, I_{DQ} = 100mA, V_G = -2.3V Typical, CW

Parameter	Min	Typical	Max	Units
Operational Frequency Range	2		6	GHz
Small Signal Gain		>22		dB
Input Return Loss		>10		dB
Output Return Loss		>10		dB
Noise Figure		1		dB
Output Power at 1 dB Gain Compression		>18		dBm
Output TOI at Pout/tone = 18 dBm		30		dBm
Gain Temperature Coefficient		-0.03		dB/°C
Noise Figure Temperature Coefficient		0.007		dB/°C

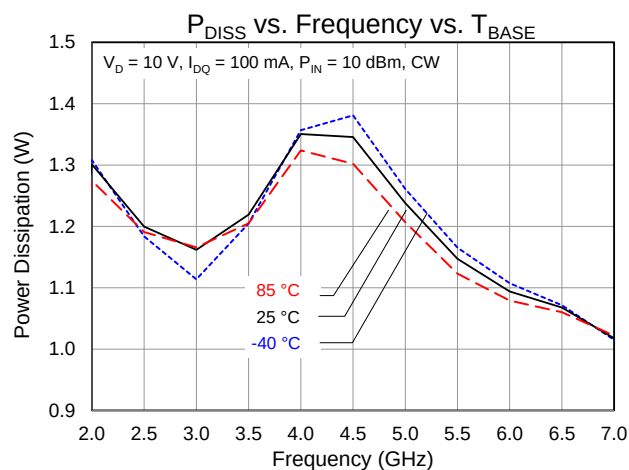
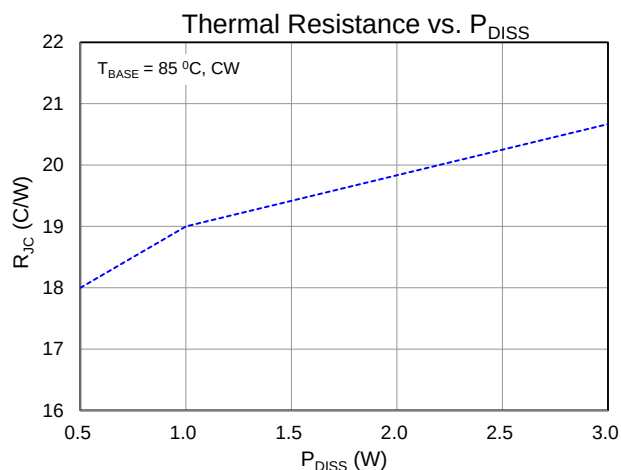
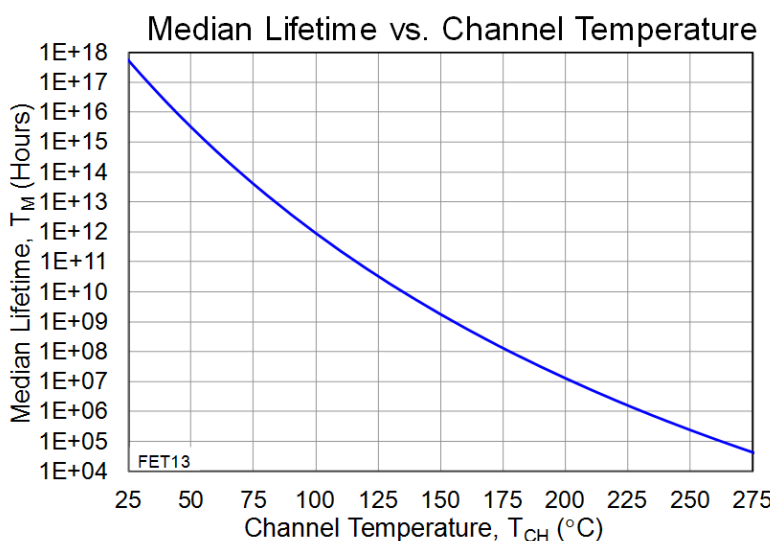
Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) ⁽¹⁾	$T_{base} = 85^\circ\text{C}$, $V_D = 10\text{ V}$ (CW)	19	$^\circ\text{C/W}$
Channel Temperature (T_{CH}) (Under RF drive)	$I_{DQ} = 100\text{ mA}$, $I_{D_Drive} = 195\text{ mA}$	110	$^\circ\text{C}$
Median Lifetime (T_M)	$P_{IN} = 10\text{ dBm}$, $P_{OUT} = 28\text{ dBm}$, $Freq = 4\text{ GHz}$, $P_{DISS} = 1.3\text{ W}$	2.3×10^{11}	Hrs

Notes:

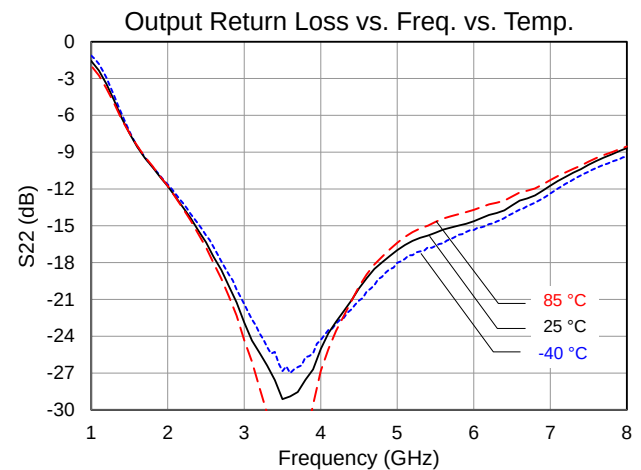
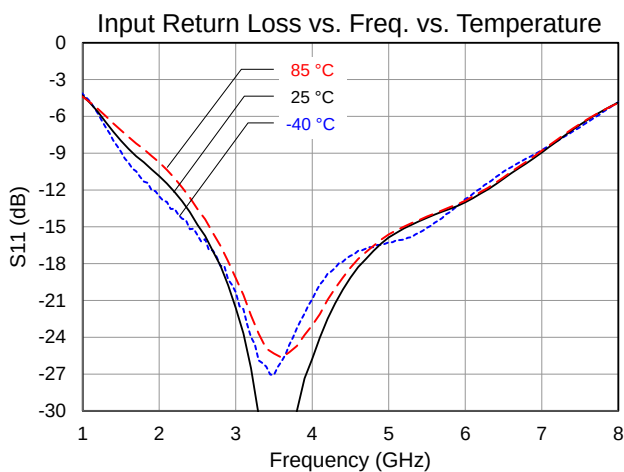
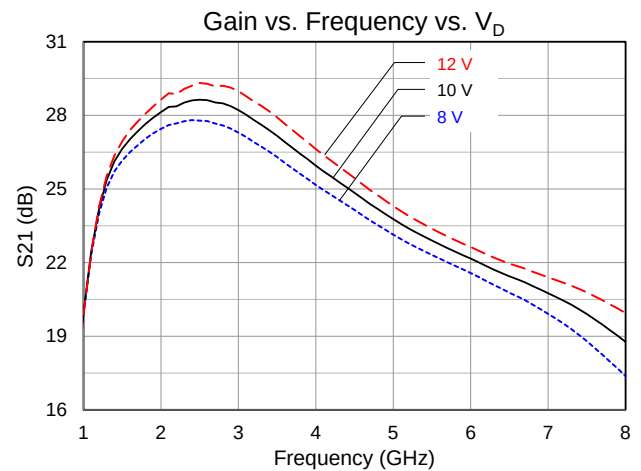
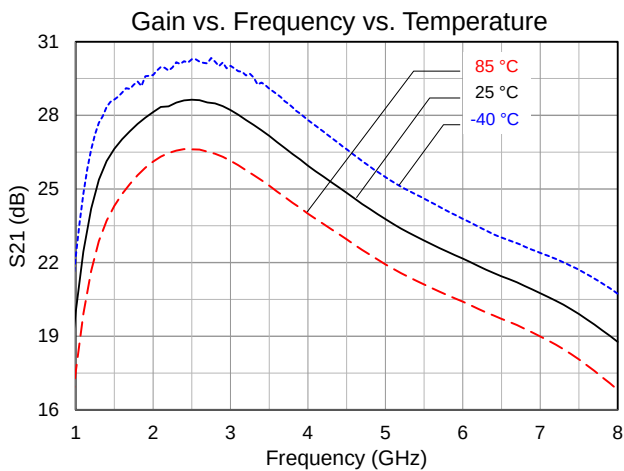
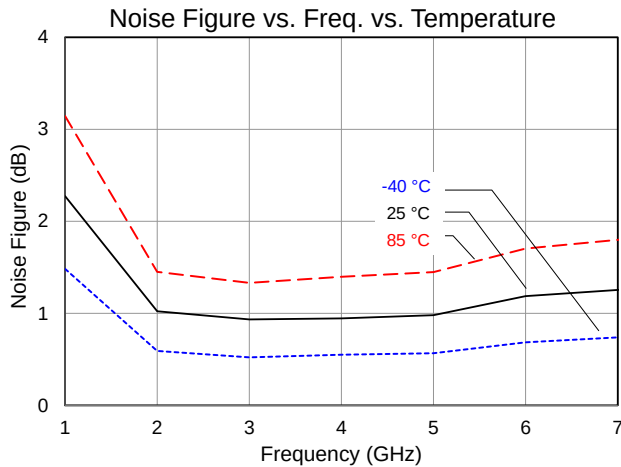
1. Thermal resistance measured at back of the package.

Test Conditions: $V_D = 40\text{ V}$; Failure Criteria is 10% reduction in I_{D_MAX}



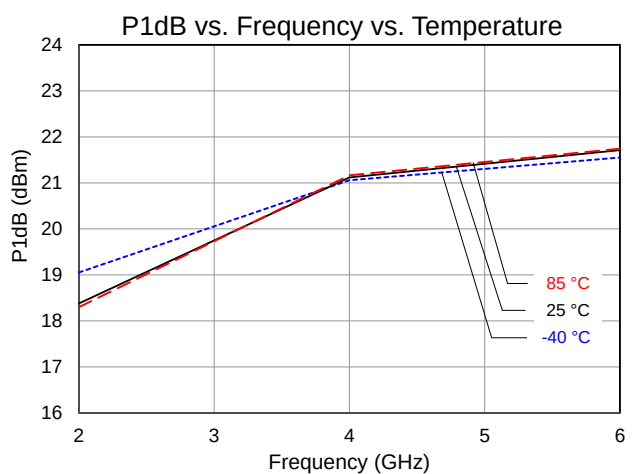
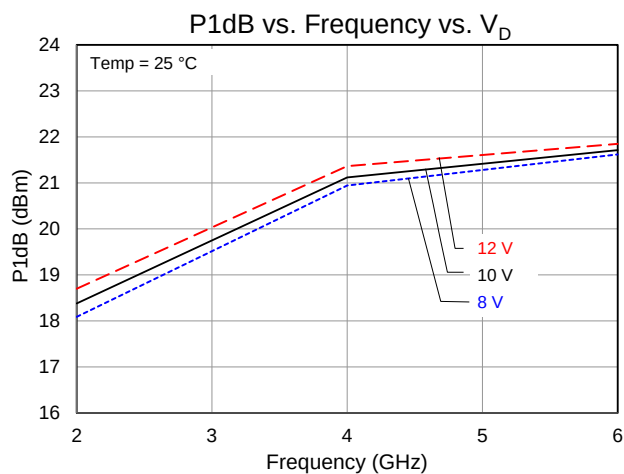
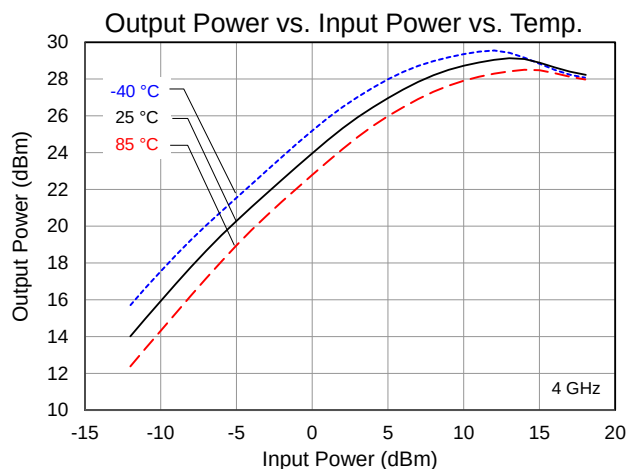
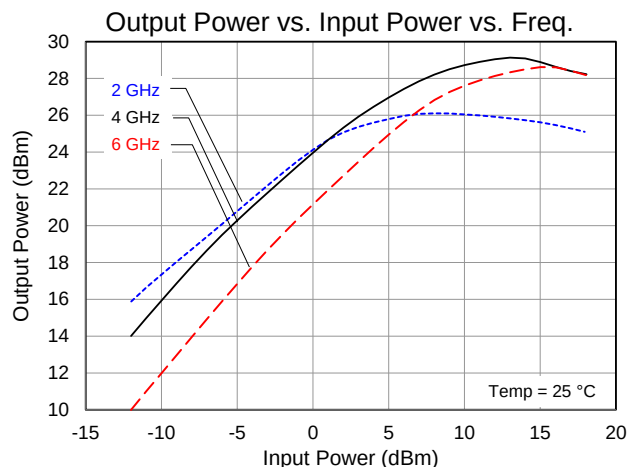
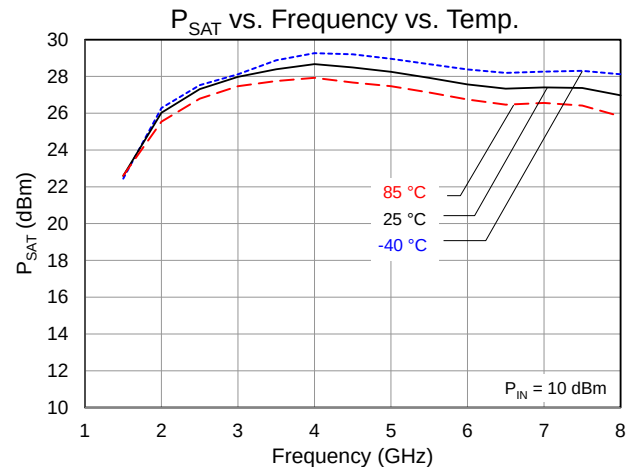
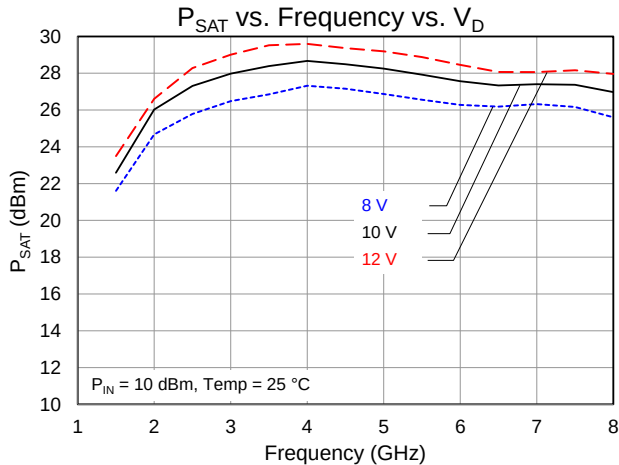
Typical Performance: Small Signal

Conditions unless otherwise specified: $V_D = 10\text{ V}$, $I_{DQ} = 100\text{ mA}$, $V_G = -2.3\text{ V}$ Typical, CW



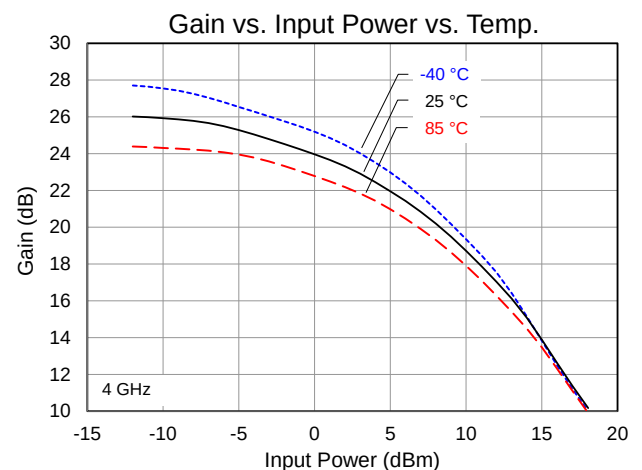
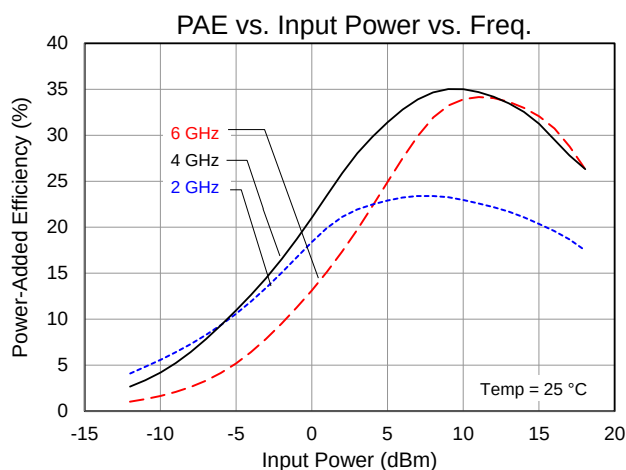
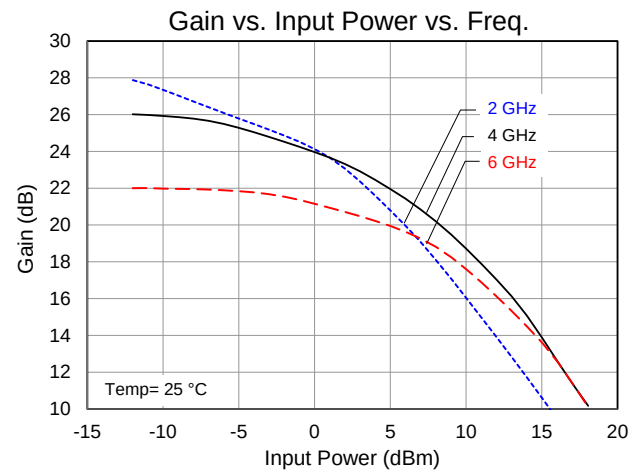
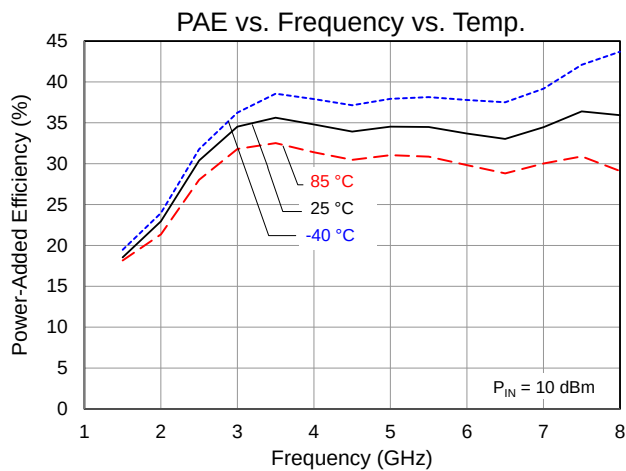
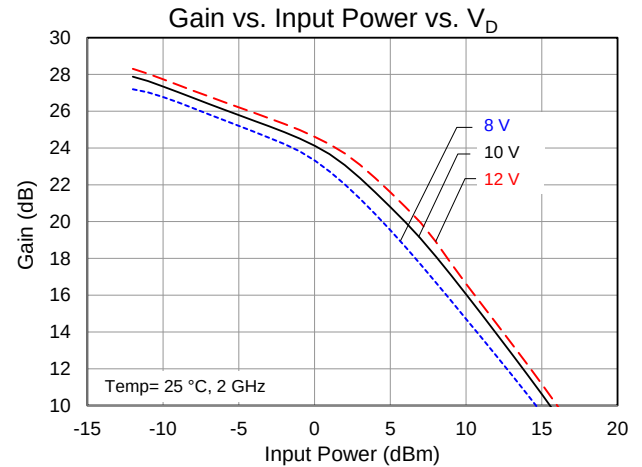
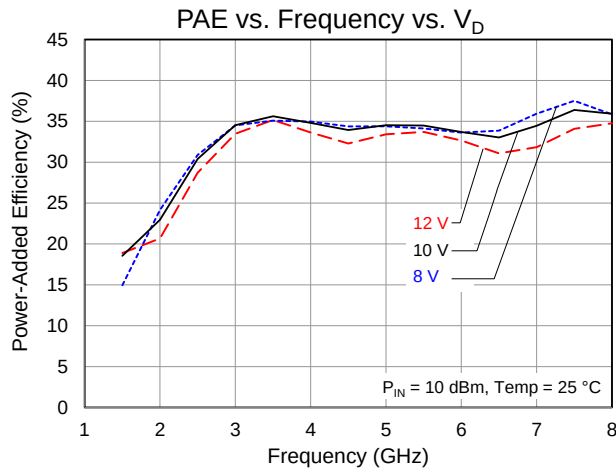
Typical Performance: Large Signal

Conditions unless otherwise specified: $V_D = 10\text{ V}$, $I_{DQ} = 100\text{ mA}$, $V_G = -2.3\text{ V}$ Typical, CW



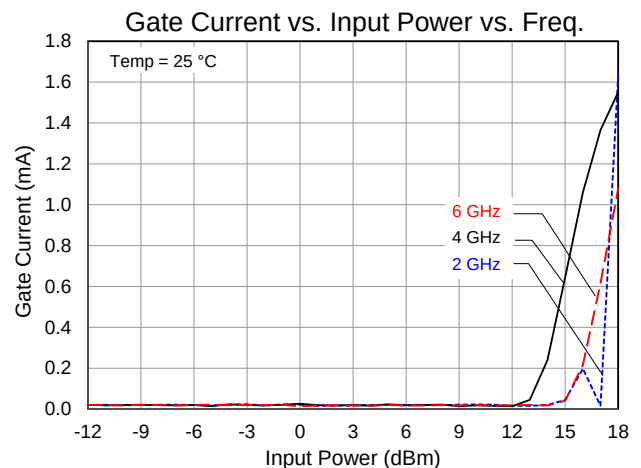
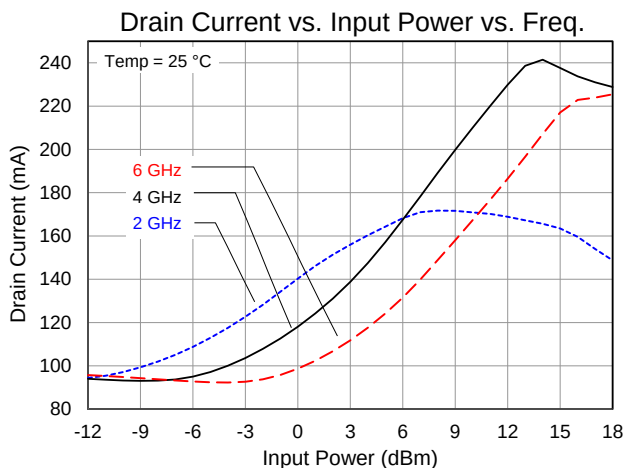
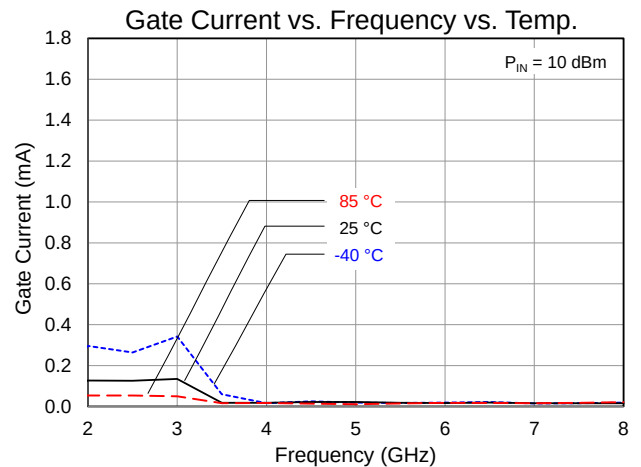
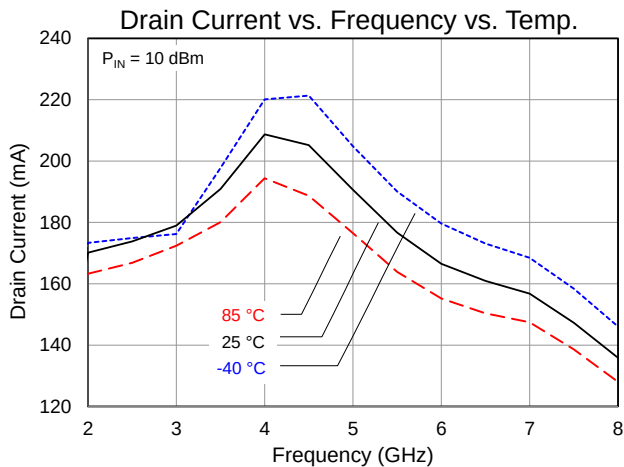
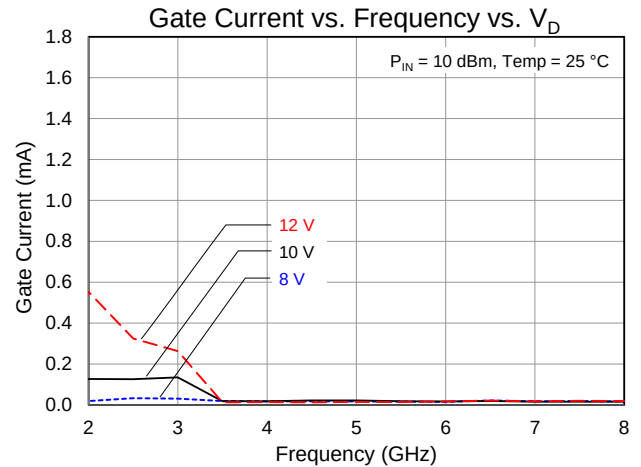
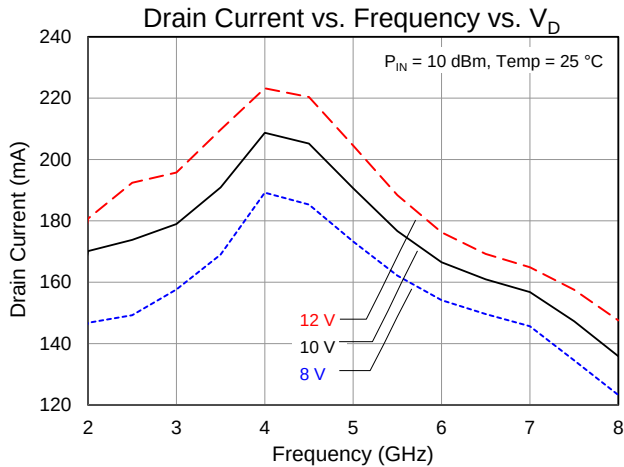
Typical Performance: Large Signal

Conditions unless otherwise specified: $V_D = 10\text{ V}$, $I_{DQ} = 100\text{ mA}$, $V_G = -2.3\text{ V}$ Typical, CW



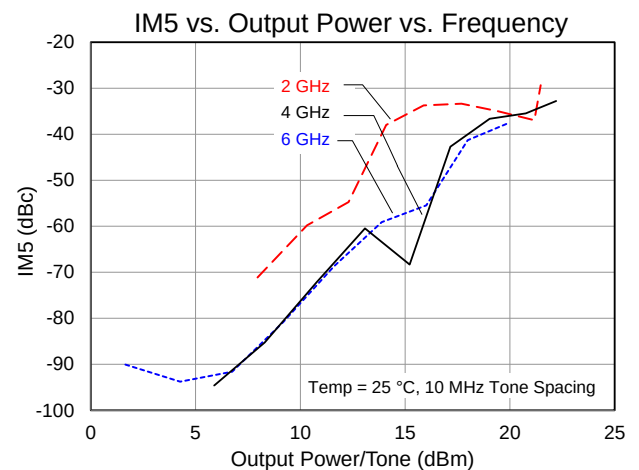
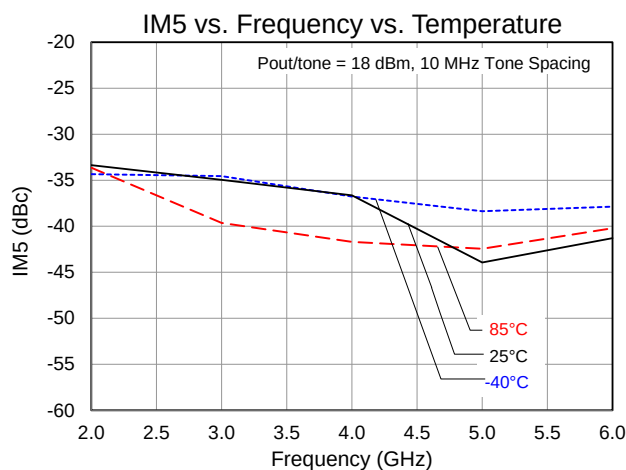
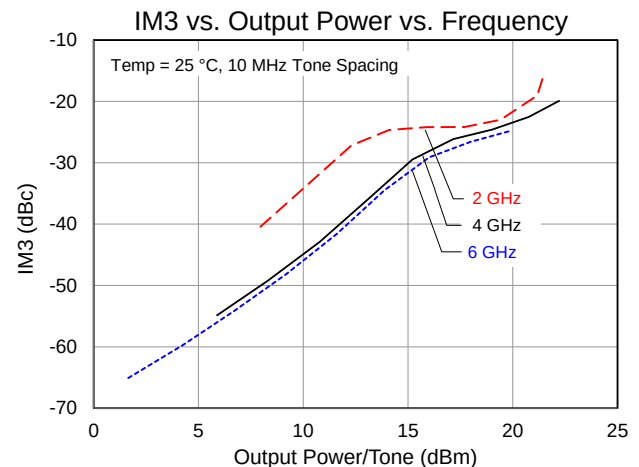
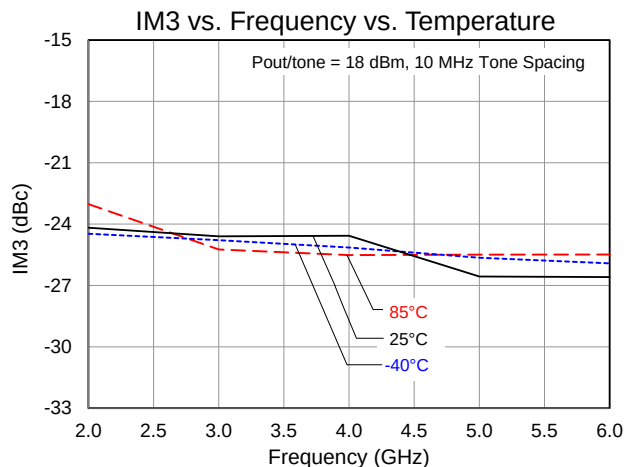
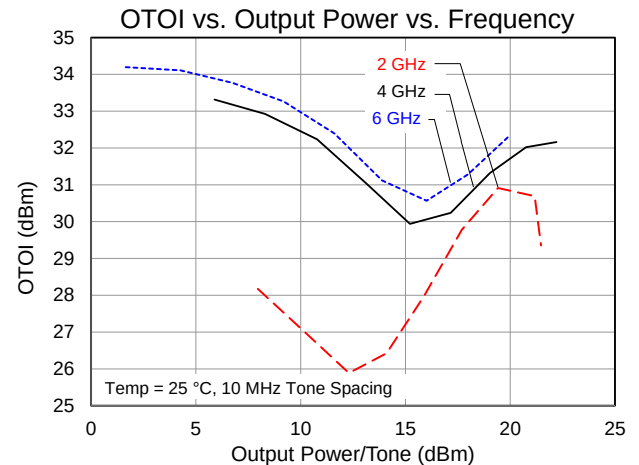
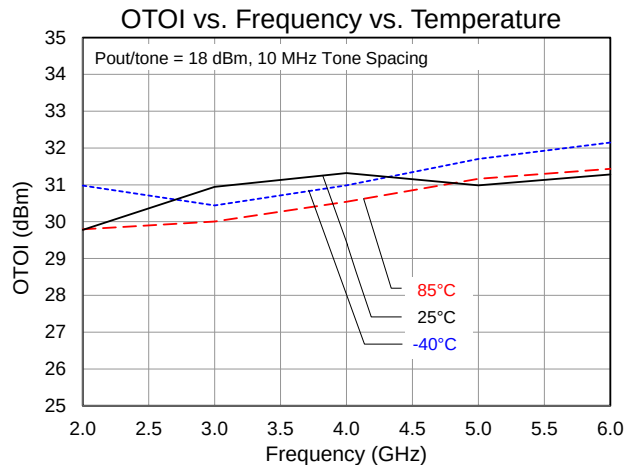
Typical Performance: Large Signal

Conditions unless otherwise specified: $V_D = 10\text{ V}$, $I_{DQ} = 100\text{ mA}$, $V_G = -2.3\text{ V}$ Typical, CW



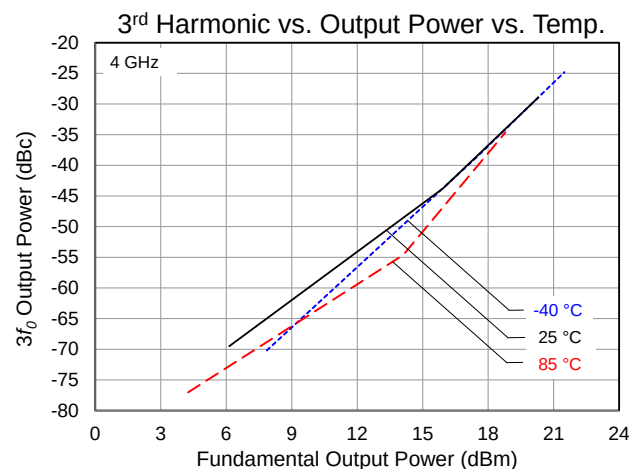
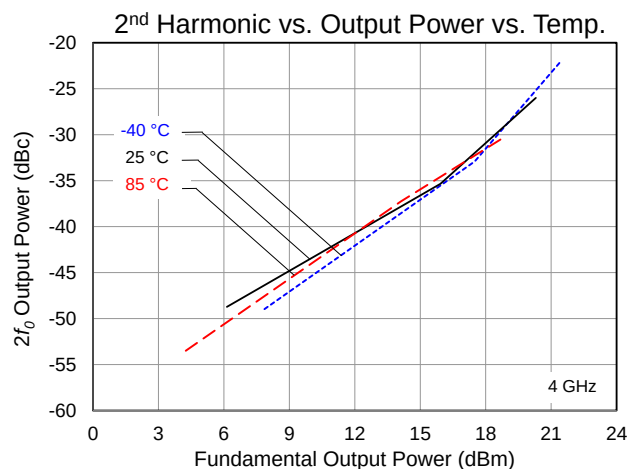
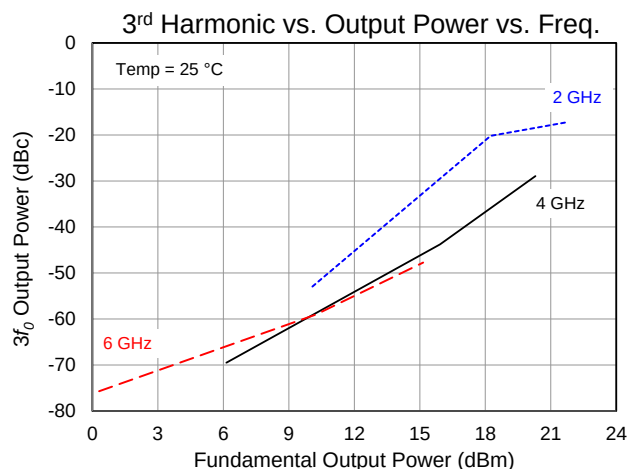
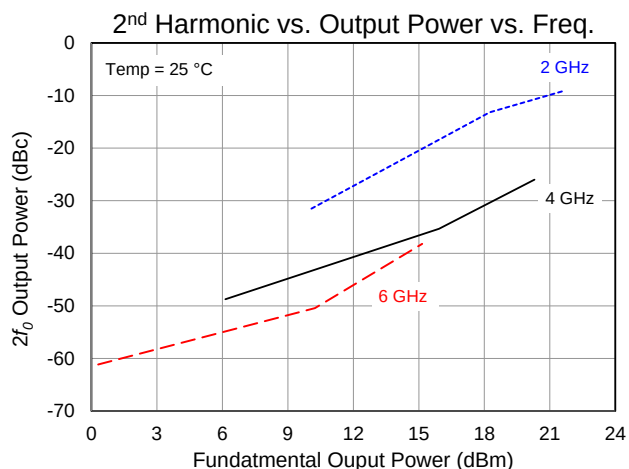
Typical Performance: Linearity

Conditions unless otherwise specified: $V_D = 10\text{ V}$, $I_{DQ} = 100\text{ mA}$, $V_G = -2.3\text{ V}$ Typical, CW

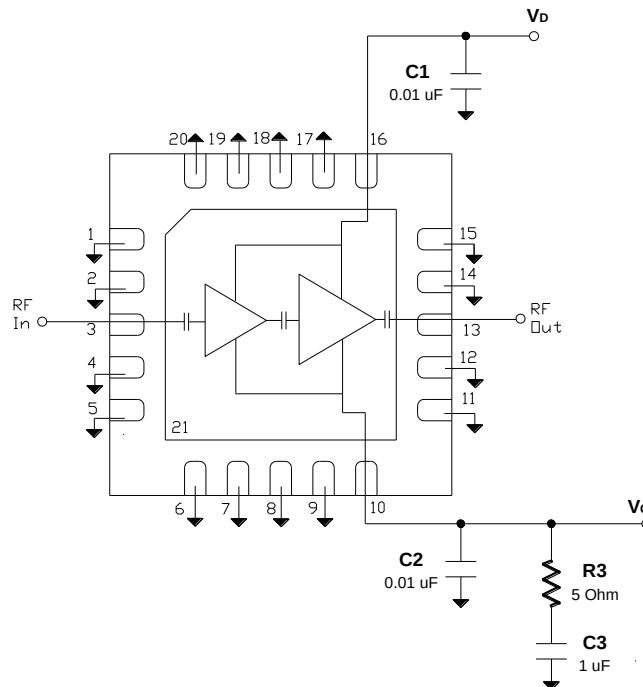


Typical Performance: Harmonics

Conditions unless otherwise specified: $V_D = 10\text{ V}$, $I_{DQ} = 100\text{ mA}$, $V_G = -2.3\text{ V}$ Typical, CW



Application Information



Bias-up Procedure

1. Set I_D limit to 300 mA, I_G limit to 3 mA
2. Apply -5 V to V_G for pinch off
3. Apply +10 V to V_D
4. Adjust V_G more positive until $I_{DQ} = 100$ mA ($V_G \sim -2.3$ V Typical)
5. Apply RF signal

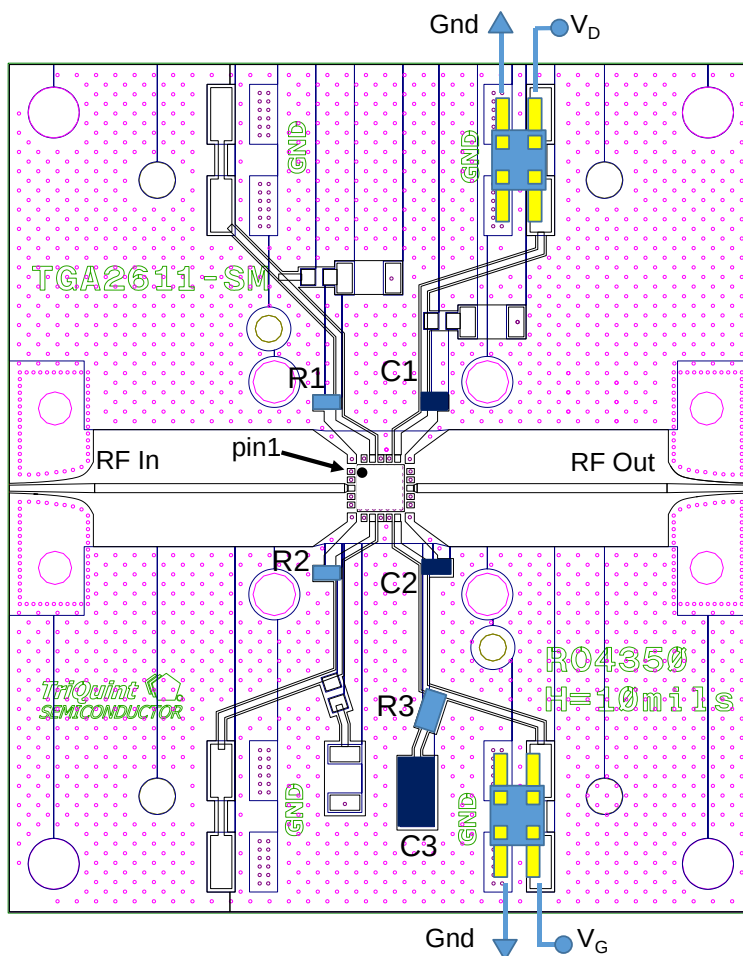
Bias-down Procedure

1. Turn off RF signal
2. Reduce V_G to -5V. Ensure $I_{DQ} \sim 0$ mA
3. Set V_D to 0V
4. Turn off V_D supply
5. Turn off V_G supply

Pin Description

Pin No.	Symbol	Description
1, 2, 4-9, 11, 12, 14, 15, 17-20	N/C	Recommend grounding on PCB
3	RF_{IN}	Input; matched to 50 Ω ; DC blocked
10	V_G	Gate voltage; bias network is required; see recommended Application Information above.
13	RF_{OUT}	Output; matched to 50 Ω ; DC blocked
16	V_D	Drain voltage; bias network is required; see recommended Application Information above.
21	Gnd	Ground Paddle. Multiple vias should be employed to minimize inductance and thermal resistance.

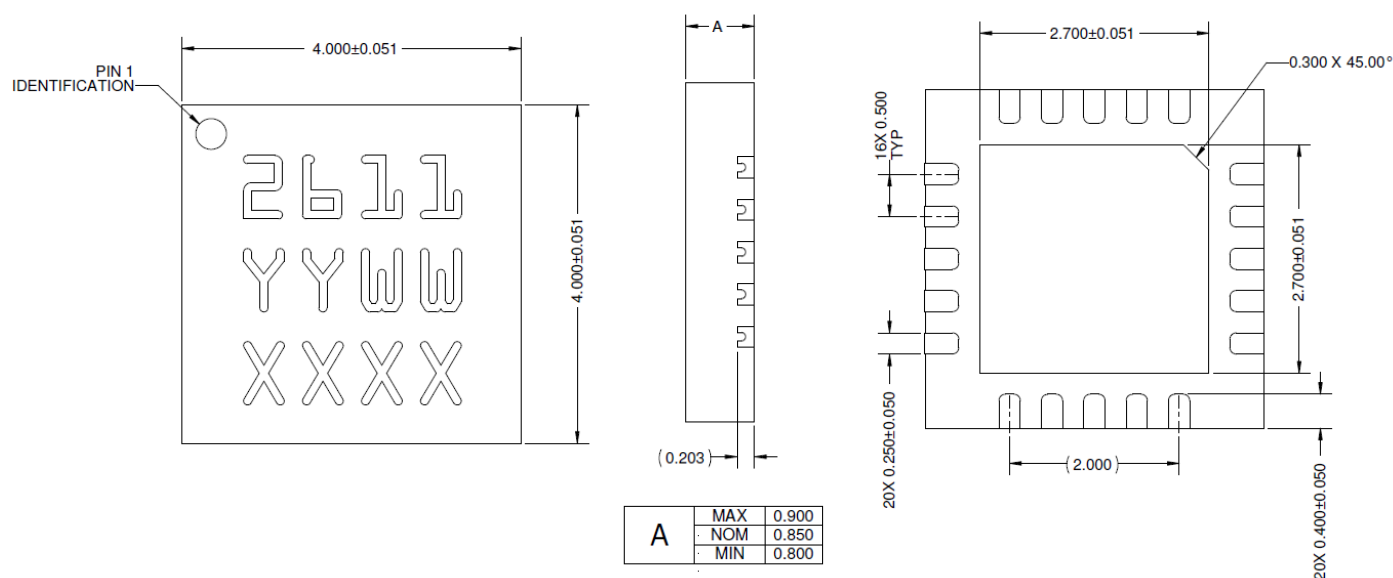
Evaluation Board



Bill of Material

Reference Des.	Value	Description	Manuf.	Part Number
C1, C2	0.01 μ F	Cap, 0402, 50 V, 10%, X7R	Various	
C3	1 μ F	Cap, 1206, 50 V, 10%, X7R	Various	
R1, R2	0 Ohms	Res, 0402, 5% (Required for above EVB design)	Various	
R3	5 Ohms	Res, 0603, 5%	Various	

Mechanical Information



Units: mm

Tolerances: unless specified

x.xx = ± 0.25

x.xxx = ± 0.127

x.xxxx = ± 0.0254

angles = 0.5°

Materials:

Base: Cu alloy

All metalized features are NiPdAu plated

Part is mold encapsulated

Marking:

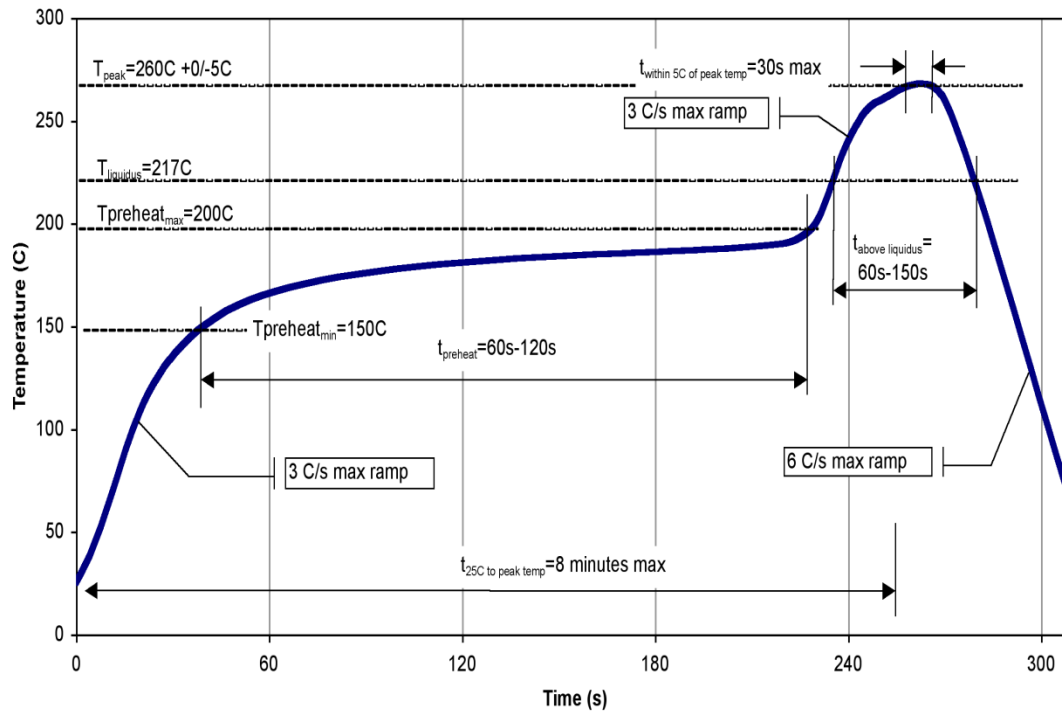
2611: Part number

YY: Part Assembly year

WW: Part Assembly week

XXXX: Lot ID

Recommended Soldering Temperature Profile



Product Compliance Information

ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: TBD
Value: TBD
Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

MSL Rating

Level TBD at TBD°C convection reflow
The part is rated Moisture Sensitivity Level TBD at TBD°C
per JEDEC standard IPC/JEDEC J-STD-020.

ECCN

US Department of Commerce: EAR99

Solderability

Compatible with the latest version of J-STD-020, Lead-free solder, 260°C

RoHS Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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Fax: +1.972.994.8504

For technical questions and application information: Email: info-products@triquint.com

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